

M.2 (P42)

3IE6 B+M Key

Series

Customer: _____

Customer

**Part
Number:** _____

Innodisk

**Part
Number:** _____

Innodisk

Model Name: _____

Date: _____

Innodisk Approver	Customer Approver

Table of contents

1. PRODUCT OVERVIEW	7
1.1 INTRODUCTION OF INNODISK M.2 (P42) 3IE6.....	7
1.2 PRODUCT VIEW AND MODELS.....	7
1.3 PCIe INTERFACE.....	8
2. PRODUCT SPECIFICATIONS.....	8
2.1 CAPACITY AND DEVICE PARAMETERS.....	8
2.2 PERFORMANCE	9
2.3 ELECTRICAL SPECIFICATIONS	10
2.3.1 Power Requirement.....	10
2.3.2 Power Consumption.....	10
2.4 ENVIRONMENTAL SPECIFICATIONS.....	10
2.4.1 Temperature Ranges	10
2.4.2 Humidity.....	10
2.4.3 Shock and Vibration.....	10
2.4.4 Mean Time between Failures (MTBF).....	11
2.5 CE AND FCC COMPATIBILITY.....	11
2.6 RoHS COMPLIANCE.....	11
2.7 RELIABILITY.....	12
2.8 TRANSFER MODE.....	12
2.9 PIN ASSIGNMENT.....	13
2.10 MECHANICAL DIMENSIONS	15
2.11 ASSEMBLY WEIGHT	16
2.12 SEEK TIME	16
2.13 NAND FLASH MEMORY.....	16
2.14 HEAT-SPREADING COPPER LAYER	16
3. THEORY OF OPERATION.....	17
3.1 OVERVIEW.....	17
3.2 PCIe GEN III x 4 CONTROLLER	17
3.3 ERROR DETECTION AND CORRECTION.....	18
3.4 WEAR-LEVELING.....	18
3.5 BAD BLOCKS MANAGEMENT.....	18
3.6 GARBAGE COLLECTION/TRIM.....	18
3.7 END TO END DATA PATH PROTECTION	18
3.8 THERMAL MANAGEMENT	19
3.9 AES FUNCTION (OPTIONAL).....	19
4. INSTALLATION REQUIREMENTS.....	19
4.1 M.2 (P42) 3IE6 PIN DIRECTIONS	19

4.2 ELECTRICAL CONNECTIONS FOR M.2 (P42) 3IE6	19
4.3 DEVICE DRIVE	20
5. SMART / HEALTH INFORMATION	21
5.1 GET LOG PAGE(LOG IDENTIFIER 02H)	21
6. PART NUMBER RULE	26
7. APPENDIX	27

REVISION HISTORY

Revision	Description	Date
1.0	Official Release	Jan., 2021
1.1	Update Performance Data	Mar., 2021

List of Tables

TABLE 1: DEVICE PARAMETERS	8
TABLE 2: PERFORMANCE	9
TABLE 3: INNODISK M.2 (P42) 3IE6 POWER REQUIREMENT	10
TABLE 4: POWER CONSUMPTION	10
TABLE 5: TEMPERATURE RANGE FOR M.2 (P42) 3IE6	10
TABLE 6: SHOCK/VIBRATION TESTING FOR M.2 (P42) 3IE6	10
TABLE 7: M.2 (P42) 3IE6 MTBF	11
TABLE 8: M.2 (P42) 3IE6 TBW	12
TABLE 9: INNODISK M.2 (P42) 3IE6 PIN ASSIGNMENT	13
TABLE 10: GET LOG PAGE – SMART / HEALTH INFORMATION LOG	21

List of Figures

FIGURE 1: INNODISK M.2 (P42) 3IE6 (TYPE 2242)	7
FIGURE 2: INNODISK M.2 (P42) 3IE6 DIAGRAM	15
FIGURE 3: INNODISK M.2 (P42) 3IE6 WITH HEAT-SPREADING COPPER LAYER DIAGRAM	15
FIGURE 3: INNODISK M.2 (P42) 3IE6 BLOCK DIAGRAM	17
FIGURE 4: SIGNAL SEGMENT AND POWER SEGMENT	19

1. Product Overview

1.1 Introduction of Innodisk M.2 (P42) 3IE6

Innodisk M.2 (P42) 3IE6 is a NVM Express DRAM-less SSD designed with PCIe interface and industrial 3D TLC NAND Flash. M.2 (P42) 3IE6 supports PCIe Gen III x 2 and it is compliant with NVMe 1.3 providing excellent top and also sustained performance. With sophisticated error detection and correction (ECC) functions, the module can ensure full End-to-End data path protection that secures the data transmission between host system and NAND Flash. In addition, with embedded AES-256 bit engine, your data can be further secured.

1.2 Product View and Models

Innodisk M.2 (P42) 3IE6 is available in follow capacities with industrial 3D TLC flash ICs.

M.2 (P42) 3IE6 20GB

M.2 (P42) 3IE6 80GB

M.2 (P42) 3IE6 40GB

M.2 (P42) 3IE6 160GB

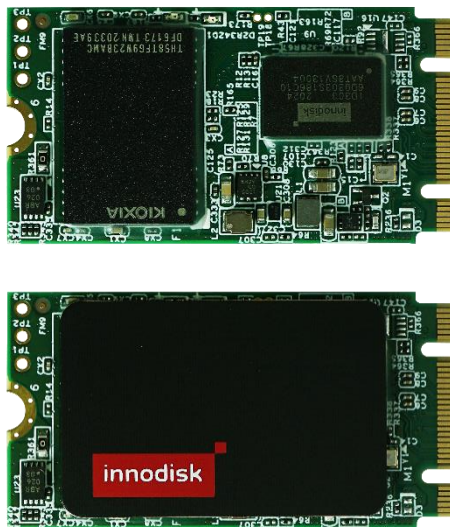


Figure 1: Innodisk M.2 (P42) 3IE6 (type 2242)

1.3 PCIe Interface

Innodisk M.2 (P42) 3IE6 supports PCIe Gen III interface and compliant with NVMe 1.3. M.2 (P42) 3IE6 can work under PCIe Gen 1, Gen 2 and Gen 3.

Most of operating system includes NVMe in-box driver now. For more information about the driver support in each OS, please visit <http://nvmeexpress.org/resources/drivers>.

2. Product Specifications

2.1 Capacity and Device Parameters

M.2 (P42) 3IE6 device parameters are shown in Table 1.

Table 1: Device parameters

Capacity	LBA	User Capacity(MB)
20GB	39,091,248	19087
40GB	78,161,328	38164
80GB	156,301,488	76319
160GB	312,581,808	152627

2.2 Performance

Burst Transfer Rate: 4 GB/s

Table 2: BiCS3 Standard & Wide-Temperature Models Performance*

Capacity	Unit	20GB	40GB	80GB	160GB
Sequential** Read (Q32T1)	MB/s	500	1,450	1,650	1,650
Sequential** Write (Q32T1)		250	500	1,000	1,450
Sustained Sequential Read (Avg.) ***		300	590	820	880
Sustained Sequential Write (Avg.) ***		230	470	900	1080
4KB Random** Read (Q32T1)	IOPS	39,000	78,000	130,000	162,000
4KB Random** Write (Q32T1)		59,000	109,000	118,000	120,000

Note: * Performance results are measured in Room Temperature with Out-of-Box devices and may vary depending on overall system setup.

Note: ** Performance results are based on CrystalDiskMark 6.0.2 with file size 1000MB. Unit of 4KB items is I.O.P.S.

Note: *** Performance results are based on AIDA64 Extreme Edition v2.00.1700 with block size 1MB of Linear Read & Write Test Item.

2.3 Electrical Specifications

2.3.1 Power Requirement

Table 3: Innodisk M.2 (P42) 3IE6 Power Requirement

Item	Symbol	Rating	Unit
Input voltage	V _{IN}	+3.3 DC +- 5%	V

2.3.2 Power Consumption

Table 4: BiCS3 Standard & Wide-Temperature Model Power Consumption *

Model	Power Consumption (mA)				
	Capacity	20GB	40GB	80GB	160GB
Read (RMS)		460	625	680	720
Write (RMS)		450	580	740	780
Idle (RMS)		165	165	170	170
Power On Peak		540	750	810	880

Note: * Current results may vary depending on system components and power circuit design.

2.4 Environmental Specifications

2.4.1 Temperature Ranges

Table 5: Temperature range for M.2 (P42) 3IE6

Temperature	Range
Operating	Standard Grade: 0°C to +70°C Industry Grade: -40°C to +85°C
Storage	-55°C to +95°C

2.4.2 Humidity

Relative Humidity: 10-95%, non-condensing

2.4.3 Shock and Vibration

Table 6: Shock/Vibration Testing for M.2 (P42) 3IE6

Reliability	Test Conditions	Reference Standards
Vibration	7 Hz to 2K Hz, 20G, 3 axes	IEC 60068-2-6
Mechanical Shock	Duration: 0.5ms, 1500 G, 3 axes	IEC 60068-2-27

2.4.4 Mean Time between Failures (MTBF)

Table 7 summarizes the MTBF prediction results for various M.2 (P42) 3IE6 configurations. The analysis was performed using a RAM Commander™ failure rate prediction.

- **Failure Rate:** The total number of failures within an item population, divided by the total number of life units expended by that population, during a particular measurement interval under stated condition.
- **Mean Time between Failures (MTBF):** A basic measure of reliability for repairable items: The mean number of life units during which all parts of the item perform within their specified limits, during a particular measurement interval under stated conditions.

Table 7: M.2 (P42) 3IE6 MTBF

Product	Condition	MTBF (Hours)
Innodisk M.2 (P42) 3IE6	Telcordia SR-332 GB, 25°C	>3,000,000

2.5 CE and FCC Compatibility

M.2 (P42) 3IE6 conforms to CE and FCC requirements.

2.6 RoHS Compliance

M.2 (P42) 3IE6 is fully compliant with RoHS directive.

2.7 Reliability

Table 8: M.2 (P42) 3IE6 TBW

Parameter	Value	
Read Cycles	Unlimited Read Cycles	
Flash endurance	30,000 P/E cycles	
Wear-Leveling Algorithm	Support	
Bad Blocks Management	Support	
Error Correct Code	Support(LDPC)	
Data Retention	Under 40°C: 10 Years at Initial NAND Status (PE cycles under 100) 1 Year at NAND Life End (PE cycles reach 30,000)	
TBW* (Total Bytes Written) Unit: TB		
Capacity	Sequential workload	Client workload
20GB	532	122
40GB	1065	378
80GB	2130	868
160GB	4260	1736
<p>* Note:</p> <ol style="list-style-type: none"> 1. Sequential: Mainly sequential write, tested by Vdbench. These are estimated values subject to update. 2. Client: Follow JESD218 Test method and JESD219A Workload, tested by ULINK. (The capacity lower than 64GB client workload is not specified in JEDEC219A, the values are estimated.) 3. Based on out-of-box performance. 		

2.8 Transfer Mode

M.2 (P42) 3IE6 support following transfer mode:

PCIe Gen III 4 GB/s

PCIe Gen II 2 GB/s

PCIe Gen I 1 GB/s

2.9 Pin Assignment

Innodisk M.2 (P42) 3IE6 follows standard M.2 spec, socket 2 key B + M PCIe-based SSD pinout. See Table 9 for M.2 (P42) 3IE6 pin assignment.

Table 9: Innodisk M.2 (P42) 3IE6 Pin Assignment

Signal Name	Pin #	Pin #	Signal Name
		75	GND
3.3V	74	73	GND
3.3V	72	71	GND
3.3V	70	69	NC
NC	68	67	NC
Notch	66	65	Notch
Notch	64	63	Notch
Notch	62	61	Notch
Notch	60	59	Notch
NC (Reserved)	58		
NC (Reserved)	56	57	GND
NC	54	55	REFCLKp
CLKREQ# (I/O)(0/3.3V)	52	53	REFCLKn
PERST# (I)(0/3.3V)	50	51	GND
NC	48	49	PERp0
NC	46	47	PERn0
NC	44	45	GND
NC (reserved for SMB_DATA)	42	43	PETp0
NC (reserved for SMB_CLK)	40	41	PETn0
NC	38	39	GND
NC	36	37	PERp1
NC	34	35	PERn1
NC	32	33	GND
NC	30	31	PETp1
NC	28	29	PETn1
NC	26	27	GND
NC	24	25	NC
NC	22	23	NC
NC	20	21	GND
Notch	18	19	Notch
Notch	16	17	Notch
Notch	14	15	Notch

Notch	12	13	Notch
LED1#	10	11	NC
NC	8	9	NC
NC	6	7	NC
3.3V	4	5	NC
3.3V	2	3	GND
		1	GND

2.10 Mechanical Dimensions

M.2 Type 2242-D2-B-M

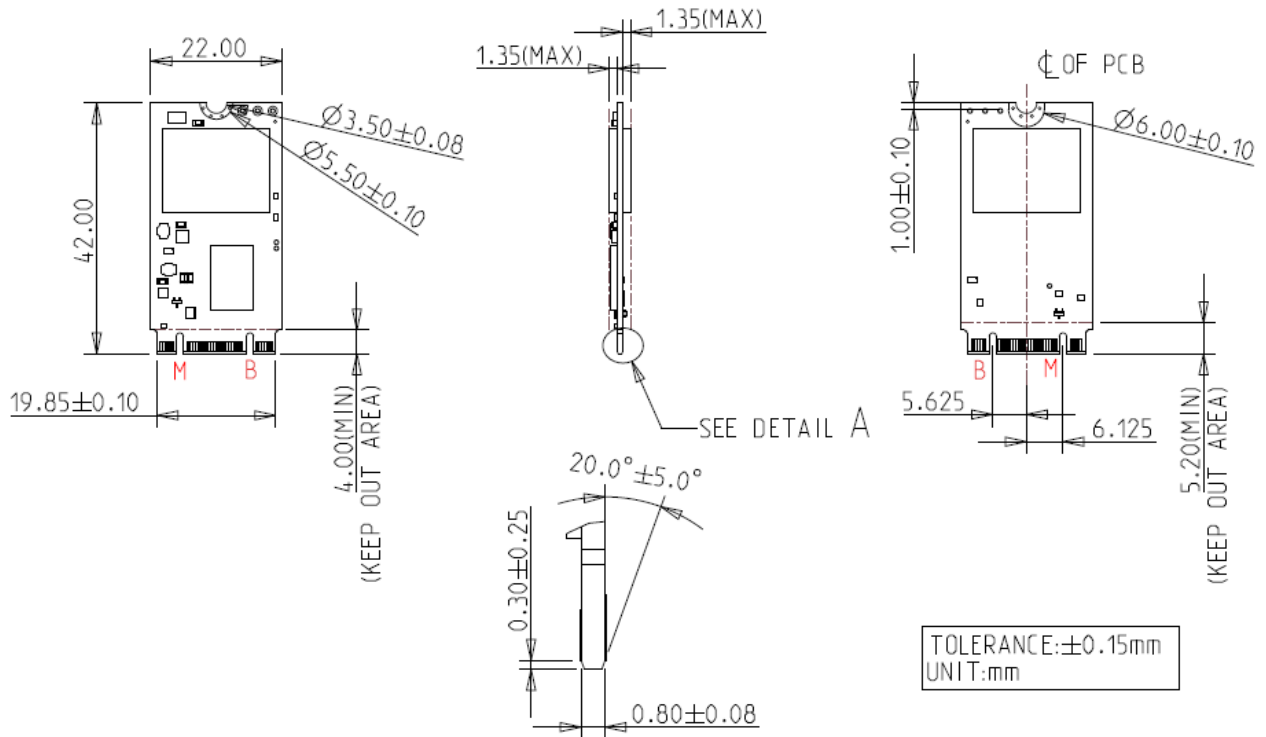


Figure 2: Innodisk M.2 (P42) 3IE6 diagram

M.2 Type 2242-D2-B-M with heat-spreading copper layer

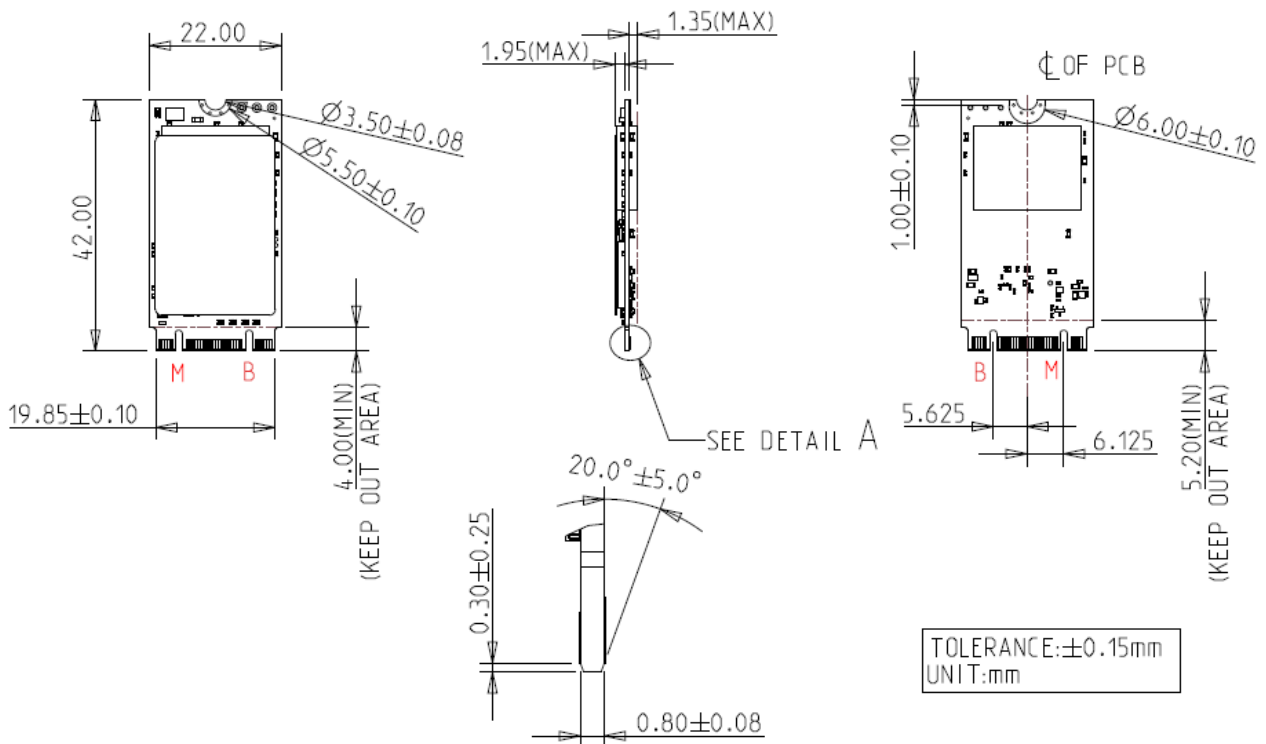


Figure 3: Innodisk M.2 (P42) 3IE6 with heat-spreading copper layer diagram

2.11 Assembly Weight

An Innodisk M.2 (P42) 3IE6 within NAND flash ICs, 128GB's weight is 7 grams approximately.

2.12 Seek Time

Innodisk M.2 (P42) 3IE6 is not of magnetic rotating design. There is no seek or rotational latency.

2.13 NAND Flash Memory

Innodisk M.2 (P42) 3IE6 uses industrial 3D TLC NAND flash memory, which is non-volatility, high reliability and high speed memory storage.

2.14 Heat-spreading copper layer

Innodisk M.2 (P42) 3IE6 industry temperature models come with a Heat-spreading copper layer installed on top of 3IE6 with dimension of 30x20x0.25 mm. This design will increase 3IE6's height to 1.95mm max due to the thermal pad and copper layer itself.

3. Theory of Operation

3.1 Overview

Figure 2 shows the operation of Innodisk M.2 (P42) 3IE6 from the system level, including the major hardware blocks.

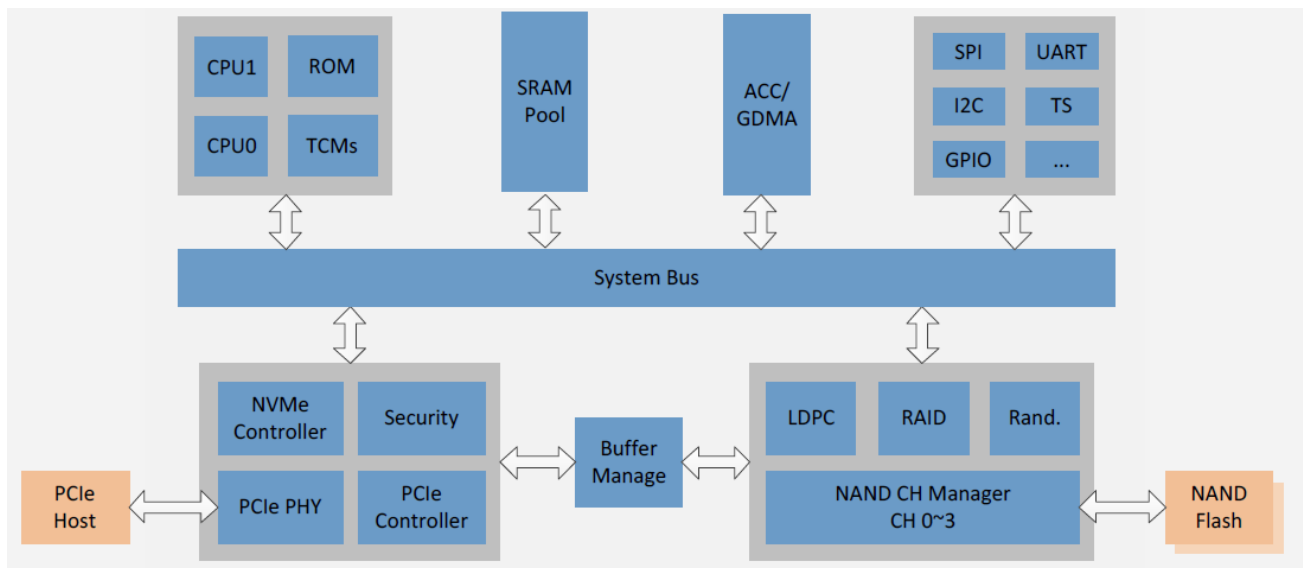


Figure 4: Innodisk M.2 (P42) 3IE6 Block Diagram

Innodisk M.2 (P42) 3IE6 integrates a PCIe Gen III x4 controller and NAND flash memories. Communication with the host occurs through the host interface, using the standard NVM protocol. Communication with the flash device(s) occurs through the flash interface.

3.2 PCIe Gen III x 4 Controller

Innodisk M.2 (P42) 3IE6 is designed with innodisk ID303, a PCIe Gen IIIx4 controller which is compliant with NVMe 1.3, up to 32.0Gbps transfer speed. In addition, it is compliant with PCIe Gen. 1, Gen. 2 and Gen. 3 specification. The controller supports up to four channels for flash interface.

3.3 Error Detection and Correction

Innodisk M.2 (P42) 3IE6 is designed with hardware LDPC ECC engine with hard-decision and soft-decision decoding. Low-density parity-check (LDPC) codes have excellent error correcting performance close to the Shannon limit when decoded with the belief-propagation (BP) algorithm using soft-decision information.

3.4 Wear-Leveling

Flash memory can be erased with a limited number of cycles. This number is called the **erase cycle limit** or **write endurance limit** and is defined by the flash NAND vendor. The erase cycle limit applies to each individual erase block in the flash device.

Innodisk M.2 (P42) 3IE6 uses a combination of two types of wear leveling- dynamic and static wear leveling- to distribute write cycling across an SSD and balance erase count of each block, thereby extending device lifetime.

3.5 Bad Blocks Management

Bad Blocks are blocks that contain one or more invalid bits whose reliability are not guaranteed. The Bad Blocks may be presented while the SSD is shipped, or may develop during the lifetime of the SSD. When a Bad Block is detected, it will be flagged as unusable block by firmware. The SSD implement Bad Blocks management that consists of Bad Blocks replacement and Error Correcting to avoid data error occurred. The functions will be enabled automatically to transfer data from Bad Blocks to spare blocks, and correct error bit.

3.6 Garbage Collection/TRIM

Garbage collection and TRIM technology is used to maintain data consistency and perform continual data cleansing on SSDs. It runs as a background process, freeing up valuable controller resources while sorting good data into available blocks, and deleting bad blocks. It also significantly reduces write operations to the drive, thereby increasing the SSD's speed and lifespan.

3.7 End to End Data Path Protection

End-to-end Data Path Protection that secures the data transmission between host system and NAND Flash. In the transmission path, no matter in or out, all buffer and storage implement Error Code Correction that optimizes the data integrity in the whole transmission of SSD.

3.8 Thermal Management

M.2 (P42) 3IE6 has built-in thermal sensor which can detect environment temperature of SSD. In the meantime, firmware will monitor the thermal sensor to prevent any failure of overheating. During extreme temperature, firmware will adjust the data transfer behavior to maintain the SSD’s reliable operation.

3.9 AES function (In-Dev.)

M.2 (P42) 3IE6 has built-in AES-128/256 hardware encryption engine to encode and decode data to ensure efficiency and data security. In other words, there is no impact on CPU performance, as the controller will handle all encryption and decryption.

4. Installation Requirements

4.1 M.2 (P42) 3IE6 Pin Directions

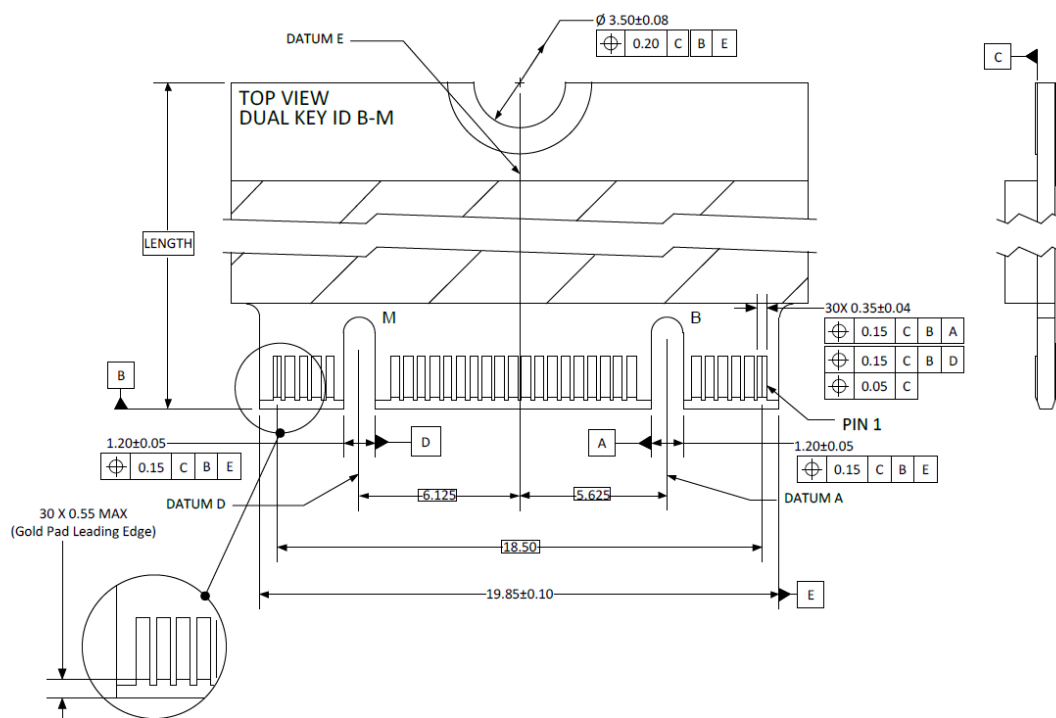


Figure 5: Signal Segment and Power Segment

4.2 Electrical Connections for M.2 (P42) 3IE6

M.2 interconnection is based on a 75-position Edge Card connector. The 75-position connector is intended to be keyed to distinguish between families of host interfaces and the various sockets used in general Platforms. M.2(P42) 3IE6 is compliant with M.2 Socket 2 key B + M.

4.3 Device Drive

M.2(P42) 3IE6 is compliant with NVMe 1.3. Both Operation System and BIOS should include NVMe driver to compatible with NVMe device. Nowadays, most of OS includes NVMe in-box driver now. For more information about the driver support in each OS, please visit the website <http://nvmexpress.org/resources/drivers>. For BIOS NVMe driver support please contact with motherboard manufacturers.

5. SMART / Health Information

This log page is used to provide SMART and general health information. The information provided is over the life of the controller and is retained across power cycles. More details about Set Features command; please refer to NVM Express 1.3

5.1 Get Log Page(Log Identifier 02h)

Innodisk 3IE6 series SMART / Health Information Log are listed in following table.

Table 10: Get Log Page – SMART / Health Information Log

Bytes	Description														
0	<p>Critical Warning: This field indicates critical warnings for the state of the controller. Each bit corresponds to a critical warning type; multiple bits may be set. If a bit is cleared to '0', then that critical warning does not apply. Critical warnings may result in an asynchronous event notification to the host. Bits in this field represent the current associated state and are not persistent.</p> <table border="1"> <thead> <tr> <th>Bit</th> <th>Definition</th> </tr> </thead> <tbody> <tr> <td>0</td> <td>If set to '1', then the available spare space has fallen below the threshold.</td> </tr> <tr> <td>1</td> <td>If set to '1', then a temperature is above an over temperature threshold or below an under</td> </tr> <tr> <td>2</td> <td>If set to '1', then the NVM subsystem reliability has been degraded due to significant media related</td> </tr> <tr> <td>3</td> <td>If set to '1', then the media has been placed in read only mode.</td> </tr> <tr> <td>4</td> <td>If set to '1', then the volatile memory backup device has failed. This field is only valid if the</td> </tr> <tr> <td>7:5</td> <td>Reserved</td> </tr> </tbody> </table>	Bit	Definition	0	If set to '1', then the available spare space has fallen below the threshold.	1	If set to '1', then a temperature is above an over temperature threshold or below an under	2	If set to '1', then the NVM subsystem reliability has been degraded due to significant media related	3	If set to '1', then the media has been placed in read only mode.	4	If set to '1', then the volatile memory backup device has failed. This field is only valid if the	7:5	Reserved
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3	If set to '1', then the media has been placed in read only mode.														
4	If set to '1', then the volatile memory backup device has failed. This field is only valid if the														
7:5	Reserved														
1:2	<p>Composite Temperature: Contains a value corresponding to a temperature in degrees Kelvin that represents the current composite temperature of the controller and namespace(s) associated with that controller. The manner in which this value is computed is implementation specific and may not represent the actual temperature of any physical point in the NVM subsystem. The value of this field may be used to trigger an asynchronous event.</p>														

	Warning and critical overheating composite temperature threshold values are reported by the WCTEMP and CCTEMP fields in the Identify Controller data structure.
3	Available Spare: Contains a normalized percentage (0 to 100%) of the remaining spare capacity available.
4	Available Spare Threshold: When the Available Spare falls below the threshold indicated in this field, an asynchronous event completion may occur. The value is indicated as a normalized percentage (0 to 100%).
5	Percentage Used: Contains a vendor specific estimate of the percentage of NVM subsystem life used based on the actual usage and the manufacturer's prediction of NVM life. A value of 100 indicates that the estimated endurance of the NVM in the NVM subsystem has been consumed, but may not indicate an NVM subsystem failure. The value is allowed to exceed 100. Percentages greater than 254 shall be represented as 255. This value shall be updated once per power-on hour (when the controller is not in a sleep state). Refer to the JEDEC JESD218A standard for SSD device life and endurance measurement techniques.
6:31	Reserved
32:47	Data Units Read: Contains the number of 512 byte data units the host has read from the controller; this value does not include metadata. This value is reported in thousands (i.e., a value of 1 corresponds to 1000 units of 512 bytes read) and is rounded up. When the LBA size is a value other than 512 bytes, the controller shall convert the amount of data read to 512 byte units. For the NVM command set, logical blocks read as part of Compare and Read operations shall be included in this value.
48:63	Data Units Written: Contains the number of 512 byte data units the host has written to the controller; this value does not include metadata. This value is reported in thousands (i.e., a value of 1 corresponds to 1000 units of 512 bytes written) and is rounded up. When the LBA size is a value other than 512 bytes, the controller shall convert the amount of data written to 512 byte units. For the NVM command set, logical blocks written as part of Write operations shall be included in this value. Write Uncorrectable commands shall not impact this value.
64:79	Host Read Commands: Contains the number of read commands completed by the controller. For the NVM command set, this is the number of Compare and Read commands.

80:95	<p>Host Write Commands: Contains the number of write commands completed by the controller.</p> <p>For the NVM command set, this is the number of Write commands.</p>
96:111	<p>Controller Busy Time: Contains the amount of time the controller is busy with I/O commands. The controller is busy when there is a command outstanding to an I/O Queue (specifically, a command was issued via an I/O Submission Queue Tail doorbell write and the corresponding completion queue entry has not been posted yet to the associated I/O Completion Queue). This value is reported in minutes.</p>
112:127	<p>Power Cycles: Contains the number of power cycles.</p>
128:143	<p>Power On Hours: Contains the number of power-on hours. This may not include time that the controller was powered and in a non-operational power state.</p>
144:159	<p>Unsafe Shutdowns: Contains the number of unsafe shutdowns. This count is incremented when a shutdown notification (CC.SHN) is not received prior to loss of power.</p>
160:175	<p>Media and Data Integrity Errors: Contains the number of occurrences where the controller detected an unrecovered data integrity error. Errors such as uncorrectable ECC, CRC checksum failure, or LBA tag mismatch are included in this field.</p>
176:191	<p>Number of Error Information Log Entries: Contains the number of Error Information log entries over the life of the controller.</p>
192:195	<p>Warning Composite Temperature Time: Contains the amount of time in minutes that the controller is operational and the Composite Temperature is greater than or equal to the Warning Composite Temperature Threshold (WCTEMP) field and less than the Critical Composite Temperature Threshold (CCTEMP) field in the Identify Controller data structure.</p> <p>If the value of the WCTEMP or CCTEMP field is 0h, then this field is always cleared to 0h regardless of the Composite Temperature value.</p>
196:199	<p>Critical Composite Temperature Time: Contains the amount of time in minutes that the controller is operational and the Composite Temperature is greater than the Critical Composite Temperature Threshold (CCTEMP) field in the Identify Controller data structure.</p> <p>If the value of the CCTEMP field is 0h, then this field is always cleared to 0h regardless of the Composite Temperature value.</p>
200:201	<p>Temperature Sensor 1: Contains the current temperature reported by controller's temperature sensor.</p>
202:203	<p>Temperature Sensor 2: Contains the current temperature reported by external temperature sensor.</p>

204:205	Temperature Sensor 3: Contains the current temperature reported by channel zero CE zero NAND's temperature sensor.
206:207	Temperature Sensor 4: Contains the current temperature reported by last channel CE zero NAND's temperature sensor.
208:209	Temperature Sensor 5: Contains the current temperature reported by temperature sensor 5.
210:211	Temperature Sensor 6: Contains the current temperature reported by temperature sensor 6.
212:213	Temperature Sensor 7: Contains the current temperature reported by temperature sensor 7.
214:215	Temperature Sensor 8: Contains the current temperature reported by temperature sensor 8.
216:219	Thermal Management Temperature 1 Transition Count: Lower Power Active Power States or Performed Vendor Specific Thermal Management
220:223	Thermal Management Temperature 2 Transition Count: Lower Power Active Power States or Performed Vendor Specific Thermal Management
224:227	Total Time For Thermal Management Temperature 1: Duration in Lower Power Active Power States or Performed Vendor Specific Thermal Management
228:231	Total Time For Thermal Management Temperature 2: Duration in Lower Power Active Power States or Performed Vendor Specific Thermal Management
232:337	Reserved
338:345	Later Bad Count
346:353	Power-On hours Count
354:361	Drive Power Cycle Count
362:369	Total Bad Block Count
370:377	User Max Erase Count
378:385	User Avg Erase Count
386:393	Device Life
394:401	Spare Block Count
402:409	Program Fail Count
410:417	Erase Fail Count
418:425	Unexpected Power Loss Count

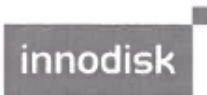
426:433	Temperature (Kelvin - K °K)
434:441	Flash ID
442:449	Later Bad Block Info (Read / Write / Erase)
450:457	Total LBAs Written (uint = 32MB)
458:465	Total LBAs Read (uint = 32MB)

6. Part Number Rule

CODE	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	
	D	H	M	2	4	-	2	0	G	D	D	1	E	C	C	D	F	-	X	X	
Definition																					
Code 1st (Disk)										Code 14th (Operation Temperature)											
D : Disk										C: Standard Grade (0°C ~ +70°C)											
Code 2nd (Feature set)										Code 15th (Internal control)											
H : iSLC series										W: Industrial Grade (-40°C ~ +85°C)											
Code 3rd ~5th (Form factor)										Code 16th (Channel of data transfer)											
M24: M.2 Type 2242-D2-M										A~Z: BGA PCB version.											
Code 7th ~9th (Capacity)										Code 17th (Flash Type)											
20G: 20GB			40: 40GB			80: 80GB				D: Dual Channels											
A60: 160GB										Q: Quad Channels											
Code 10th ~12th (Controller)										Code 18th ~20th (Customize code)											
DD1: ID303 PCIe3.0x4										F: Kioxia 3D TLC											
DD2: ID303 with AES PCIe3.0x4																					
Code 13th (Flash mode)																					
E: 64 Layer 3D TLC																					
G: 96 Layer 3D TLC																					

7. Appendix

REACH



宜鼎國際股份有限公司 Innodisk Corporation REACH Declaration

Tel:(02)7703-3000 Fax:(02) 7703-3555 Internet: <https://www.innodisk.com/>

Innodisk Corporation pursues its social responsibility for global environmental preservation by committing to be compliant with REACH regulation (REGULATION (EC) No 1907/2006). We hereby confirm that the product(s) delivered to

Innodisk P/N	Description
All Innodisk EM FLASH Products	

- contain(s) **no** hazardous substances or constituents exceeding the defined threshold 0.1 % by weight in homogenous material if not otherwise specified, as described in the candidate list table currently including 209 substances and shown on the ECHA website (<http://echa.europa.eu/de/candidate-list-table>).
- contain(s) one or more hazardous substances or constituents exceeding 0.1 % by weight in homogenous material if not otherwise specified in candidate list table. Where the threshold value is exceeded, the substances in question are to be declared in accompanying Appendix A.
- Comply with REACH Annex XVII.

Guarantor



Company name 公司名稱：Innodisk Corporation 宜鼎國際股份有限公司

Company Representative 公司代表人：Randy Chien 簡川勝



Company Representative Title 公司代表人職稱：Chairman 董事長

Date 日期：2020 / 07 / 01

RoHS 自我宣告書 (RoHS Declaration of Conformity)

Manufacturer Products: All Innodisk EM FLASH, DRAM and EP products

- 一、 宜鼎國際股份有限公司（以下稱本公司）特此保證售予貴公司之所有產品，皆符合歐盟 2011/65/EU 及 (EU) 2015/863 關於 RoHS 之規範要求。
Innodisk Corporation declares that all products sold to the company, are complied with European Union RoHS Directive (2011/65/EU) and (EU) 2015/863 requirement.
- 二、 本公司同意因本保證書或與本保證書相關事宜有所爭議時，雙方宜友好協商，達成協議。
Innodisk Corporation agrees that both parties shall settle any dispute arising from or in connection with this Declaration of Conformity by friendly negotiations.
- 三、 本公司聲明我們的產品符合 RoHS 指令的附件中(7a)、(7c-1)允許豁免。
We declare, our products permitted by the following exemptions specified in the Annex of the RoHS directive.
- ※ (7a) Lead in high melting temperature type solders (i.e. lead-based alloys containing 85% by weight or more lead).
 - ※ (7c-1) Electrical and electronic components containing lead in a glass or ceramic other than dielectric ceramic in capacitors, e.g. piezoelectric devices, or in a glass or ceramic matrix compound.

Name of hazardous substance	Limited of RoHS ppm (mg/kg)
鉛 (Pb)	< 1000 ppm
汞 (Hg)	< 1000 ppm
鎘 (Cd)	< 100 ppm
六價鉻 (Cr 6+)	< 1000 ppm
多溴聯苯 (PBBs)	< 1000 ppm
多溴二苯醚 (PBDEs)	< 1000 ppm
鄰苯二甲酸二(2-乙基己基)酯 (DEHP)	< 1000 ppm
鄰苯二甲酸丁酯苯甲酯 (BBP)	< 1000 ppm
鄰苯二甲酸二丁酯 (DBP)	< 1000 ppm
鄰苯二甲酸二異丁酯 (DIBP)	< 1000 ppm

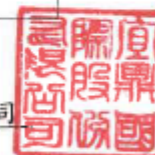
立保證書人 (Guarantor)

Company name 公司名稱: Innodisk Corporation 宜鼎國際股份有限公司

Company Representative 公司代表人: Randy Chien 簡川勝

Company Representative Title 公司代表人職稱: Chairman 董事長

Date 日期: 2020 / 03 / 03



CE



Ref. No. VXD0521A/2020
Page: 1 of 1

VERIFICATION OF COMPLIANCE

Issue Date: August 5, 2020
Applicant: Innodisk Corporation
Address: 5F., No. 237, Sec. 1, Datong Rd., Xizhi Dist.,
 New Taipei City 22161, Taiwan (R.O.C)
Manufacturer: Innodisk Corporation
Address: 5F., No. 237, Sec. 1, Datong Rd., Xizhi Dist.,
 New Taipei City 22161, Taiwan (R.O.C)
Contact Information: Web: <https://www.innodisk.com/tw/about/Corporate-Introduction>
 TEL#: 02-7703-3000#3253
 E-mail#: darren_pang@innodisk.com
Product: M.2
Brand Name/Trade Mark: Innodisk
Model/Type: M.2 (P42) 3TE6
Added Model(s): N/A
Applicable Standards: EN 55032: 2015 / AC: 2016
 CISPR 32: 2015 (Ed 2.0) / C1: 2016
 EN 61000-3-2: 2014
 EN 61000-3-3: 2013
 EN 55035: 2017
 IEC 61000-4-2: 2008; IEC 61000-4-3: 2008 + A1: 2007 + A2: 2010;
 IEC 61000-4-4: 2012; IEC 61000-4-5: 2014 + A1: 2017;
 IEC 61000-4-6: 2013 + COR1: 2015; IEC 61000-4-8: 2009;
 IEC 61000-4-11: 2004 + A1: 2017
Test Laboratory: Compliance Certification Services Inc.
 Xindian Lab
 No. 163-1, Jhongsheng Rd., Xindian Dist., New Taipei City,
 Taiwan
Test Report No. : T200722D10-E, dated on August 5, 2020
Conclusion: Based upon a review of the Test Report(s), the tested sample of the product mentioned above is deemed to comply with the requirements of the above standards.

Note: This verification is only valid for the product and configuration described and in conjunction with the test report as detailed above.

Authorised Signatory:

Compliance Certification Services Inc.
 Sam Hu
 Assistant Manager

FM-023A-R01

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Compliance Certification Services Inc.
 群智科技股份有限公司

No.163-1, Jhongsheng Rd., Xindian Dist., New Taipei City, Taiwan / 新北市新店區中生路 163-1 號
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FCC



Ref. No. VXD0520A/2020
Page: 1 of 1

VERIFICATION OF COMPLIANCE

Issue Date: August 5, 2020
Applicant: Innodisk Corporation
Address: 5F., No. 237, Sec. 1, Datong Rd., Xizhi Dist.,
 New Taipei City 22161, Taiwan (R.O.C)
Manufacturer: Innodisk Corporation
Address: 5F., No. 237, Sec. 1, Datong Rd., Xizhi Dist.,
 New Taipei City 22161, Taiwan (R.O.C)
Contact Information: Web: <https://www.innodisk.com/tw/about/Corporate-Introduction>
 TEL#: 02-7703-3000#3253
 E-mail#: darren_pang@innodisk.com
Product: M.2
Brand Name/Trade Mark: Innodisk
Model/Type: M.2 (P42) 3TE6
Added Model(s): N/A
Applicable Standards: FCC 47 CFR Part 15 Subpart B
 ANSI C63.4: 2014
 ISED ICES-003 (Issue 6)

Test Laboratory: Compliance Certification Services Inc.
 Xindian Lab
 No. 163-1, Jhongsheng Rd., Xindian Dist., New Taipei City,
 Taiwan

Test Report No. : T200722D10-D, dated on August 5, 2020

Conclusion: Based upon a review of the Test Report(s), the tested sample of the product mentioned above is deemed to comply with the requirements of the above standards.

Note: This verification is only valid for the product and configuration described and in conjunction with the test report as detailed above.

Authorised Signatory:

Compliance Certification Services Inc.
 Sam Hu
 Assistant Manager

FM-023A-R01

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MSL Statement



MSL Declaration of Conformity

1. Purpose: MSL (Moisture Sensitivity Levels) specification statement for all Innodisk products

2. Scope: For all Innodisk products

3. Reference:

4.1 JEDEC, J-STD-020

4.2 JEDEC, J-STD-033

4. Description

5.1 Innodisk Products MSL Level:

Flash /DRAM Module Level 1

BGA IC (nanoSSD family) Level 3

5.2 Floor Life Time: Refer following table

Level	Soak Requirements					
	Floor Life		Standard		Accelerated	
	Time	Cond degC/%RH	Time (hrs)	Cond degC/%RH	Time (hrs)	Cond degC/%RH
1	unlimited	<=30/85%	168+5-0	85/85	n/a	n/a
2	1 year	<=30/60%	168+5-0	85/60	n/a	n/a
2a	4 weeks	<=30/60%	60+5-0	30/60	120+1-0	60/60
3	168 hours	<=30/60%	192+5-0	30/60	40+1-0	60/60
4	72 hours	<=30/60%	96+2-0	30/60	20+0.5-0	60/60
5	48 hours	<=30/60%	72+2-0	30/60	15+0.5-0	60/60
5a	24 hours	<=30/60%	48+2-0	30/60	10+0.5-0	60/60
6	TOL	<=30/60%	TOL	30/60	n/a	60/60

Innodisk Corporation
Quality Assurance Div

Manager

Yi Chuan Chen

Date: 2018.09.27



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